

isc Silicon NPN Power Transistor

BU407

DESCRIPTION

- High Voltage: $V_{CEV} = 330V(\text{Min})$
- Fast Switching Speed-
: $t_f = 750ns(\text{Max})$
- Low Saturation Voltage-
: $V_{CE(\text{sat})} = 1.0V(\text{Max}) @ I_C = 5A$
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

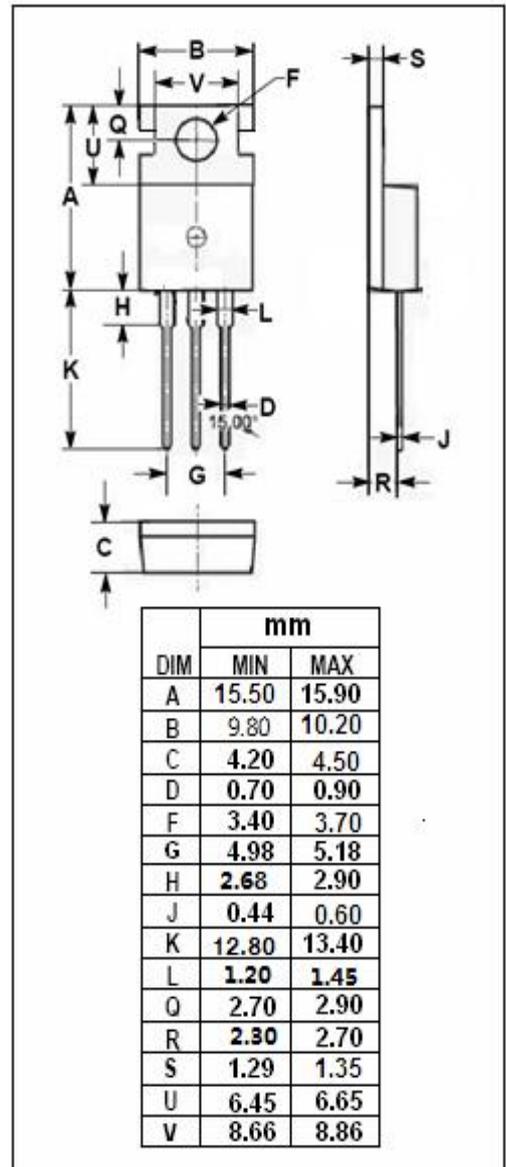
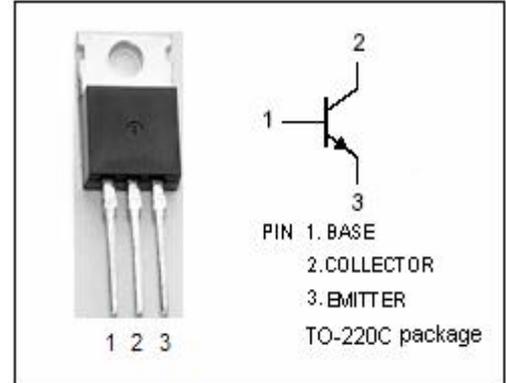
- Designed for use in horizontal deflection output stages of TV's and CRT's

ABSOLUTE MAXIMUM RATINGS($T_a = 25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	330	V
V_{CEV}	Collector-Emitter Voltage	330	V
V_{CEO}	Collector-Emitter Voltage	150	V
V_{EBO}	Emitter-Base Voltage	6	V
I_C	Collector Current-Continuous	7	A
I_{CP}	Collector Current-Peak Repetitive	10	A
I_{CP}	Collector Current- Peak (10ms)	15	A
I_B	Base Current	4	A
P_C	Collector Power Dissipation @ $T_C = 25^\circ\text{C}$	60	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-65~150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance, Junction to Case	2.08	$^\circ\text{C/W}$
$R_{th\ j-a}$	Thermal Resistance, Junction to Ambient	70	$^\circ\text{C/W}$



isc Silicon NPN Power Transistor**BU407****ELECTRICAL CHARACTERISTICS** $T_C=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{CEO(SUS)}$	Collector-Emitter Sustaining Voltage	$I_C= 50\text{mA}; I_B= 0$	150			V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C= 5\text{A}; I_B= 0.5\text{A}$			1.0	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C= 5\text{A}; I_B= 0.5\text{A}$			1.2	V
I_{CES}	Collector Cutoff Current	$V_{CE}= 330\text{V}; V_{BE}= 0$ $V_{CE}= 200\text{V}; V_{BE}= 0$			5.0 0.1	mA
I_{EBO}	Emitter Cutoff Current	$V_{EB}= 6\text{V}; I_C=0$			1.0	mA
f_T	Current-Gain—Bandwidth Product	$I_C= 0.5\text{A}; V_{CE}= 10\text{V}$	10			MHz
C_{OB}	Output Capacitance	$I_E= 0; V_{CB}= 10\text{V}; f_{test}= 1.0\text{MHz}$		80		pF
t_f	Fall Time	$I_C= 5\text{A}; I_{B1}= -I_{B2}= 0.5\text{A}$			0.75	μs

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